

Stud-Mounted Silicon Rectifier Diodes, 15 A



15 A

DESCRIPTION/FEATURES

- Low thermal impedance
- High case temperature
- Excellent reliability
- Maximum design flexibility
- Can be made to meet stringent military, aerospace and other high reliability requirements
- Compliant to RoHS directive 2002/95/EC

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		15 ⁽¹⁾	А	
	T _C	150 ⁽¹⁾	°C	
I _{FSM}	50 Hz	239	•	
	60 Hz	250 ⁽¹⁾	A	
l ² t	50 Hz	286	– A ² s	
	60 Hz	260	A ² S	
l²√t		3870	A²√s	
V _{RRM}	Range	50 to 600	V	
TJ		- 65 to 175	°C	

Note

⁽¹⁾ JEDEC registered values

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

PRODUCT SUMMARY

I_{F(AV)}

TYPE NUMBER	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = - 65 °C TO 175 °C) V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = - 65 °C TO 175 °C) V
1N3208	50 (1)	50 ⁽¹⁾
1N3209	100 (1)	100 (1)
1N3210	200 (1)	200 (1)
1N3211	300 (1)	300 (1)
1N3212	400 (1)	400 (1)
1N3213	500 (1)	500 (1)
1N3214	600 (1)	600 ⁽¹⁾

Notes

⁽¹⁾ JEDEC registered values

• Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g. 1N3208R, 1N3209R

1N3208 Series

Vishay High Power Products

Stud-Mounted Silicon Rectifier Diodes, 15 A



PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° sinusoidal conduction		15 ⁽¹⁾ 150 ⁽¹⁾	A °C
Maximum peak one cycle non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	239	A
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		250 ⁽¹⁾	
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with V _{RRM} applied following surge = 0	284	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		297	
Maximum I ² t for fusing	- l ² t	t = 10 ms	With rated V _{RRM} applied following surge, initial T _J = 150 °C	286	- A ² s
		t = 8.3 ms		260	
Maximum I ² t for individual device fusing		t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = 150 \text{ °C}$	403	
		t = 8.3 ms		368	
Maximum I²√t for individual device fusing	² √t ⁽²⁾	t = 0.1 ms to 10 ms, V_{RRM} = 0 following surge		3870	A²√s
Maximum forward voltage drop	V _{FM}	I _{F(AV)} = 15 A (47.1 A peak), T _C = 150 °C		1.5 ⁽¹⁾	V
Maximum average reverse current	I _{R(AV)}	Maximum rated $I_{F(AV)}$ and T_{C} = 150 °C		10 ⁽¹⁾	mA

Notes

(1) JEDEC registered values (2) $I^{2}t$ for time $t_{x} = I^{2}\sqrt{t} x \sqrt{t_{x}}$

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 65 to 175 ⁽¹⁾	°C	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	0.65	°C MI	
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	°C/W	
		Not lubricated thread, tighting on nut ⁽²⁾	3.4	(30)	
Maximum allowable mounting torque		Lubricated thread, tighting on nut ⁽²⁾		2.3 (20)	
(+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2	(37)	
		Lubricated thread, tighting on hexagon (3)	3.2	(28)	
Woight			28.5	g	
Weight			1	oz.	
Case style		JEDEC	DO-203A	B (DO-5)	

Notes

⁽¹⁾ JEDEC registered values

(2) Recommended for pass-through holes

⁽³⁾ Recommended for holed threaded heatsinks



1N3208 Series

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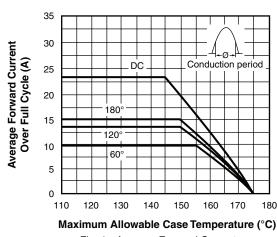
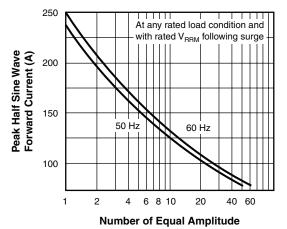


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature



Half Cycle Current Pulses (N) Fig. 2 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses

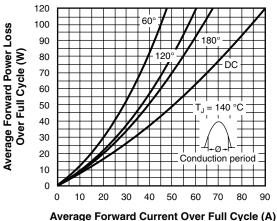
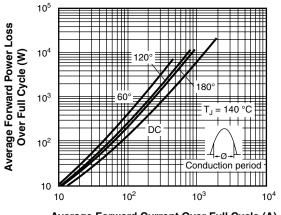


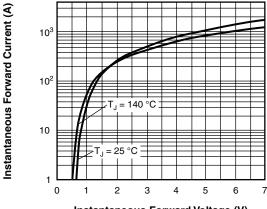
Fig. 3 - Maximum Low Level Forward Power Loss vs.

Average Forward Current



Average Forward Current Over Full Cycle (A)

Fig. 4 - Maximum High Level Forward Power Loss vs. Average Forward Current



Instantaneous Forward Voltage (V)

Fig. 5 - Maximum Forward Voltage vs. Forward Current

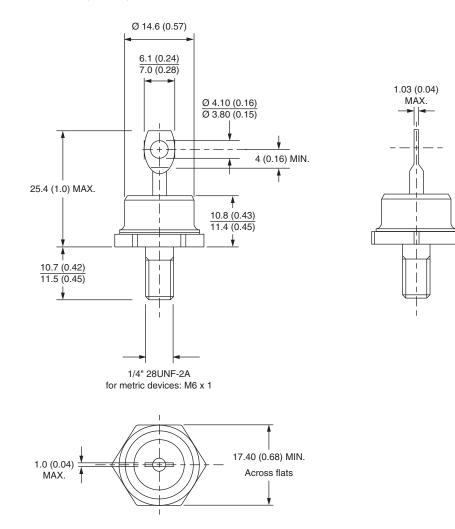
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95360	

Vishay Semiconductors

DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)

SHA





Vishay

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